


## Fast Thyristor/Diode and Thyristor/Thyristor (MAGN-A-PAK Power Modules), 200 A


**MAGN-A-PAK**
**FEATURES**

- Fast turn-off thyristor
- Fast recovery diode
- High surge capability
- Electrically isolated baseplate
- 3500 V<sub>RMS</sub> isolating voltage
- Industrial standard package
- UL approved file E78996 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level


**RoHS  
COMPLIANT**
**PRODUCT SUMMARY**

$I_{T(AV)}$	200 A
Type	Modules - Thyristor, Fast

**DESCRIPTION**

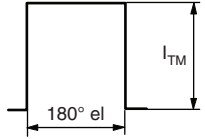
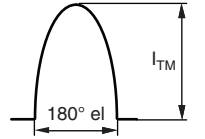
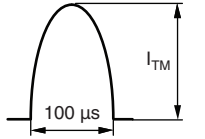
This series of MAGN-A-PAK modules are intended for applications such as self-commutated inverters, DC choppers, electronic welders, induction heating and others where fast switching characteristics are required.

**MAJOR RATINGS AND CHARACTERISTICS**

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{T(AV)}$		200	A
	$T_C$	85	°C
$I_{T(RMS)}$		444	A
$I_{TSM}$	50 Hz	7600	
	60 Hz	8000	
$I^2t$	50 Hz	290	kA <sup>2</sup> s
	60 Hz	265	
$I^2\sqrt{t}$		2900	kA <sup>2</sup> √s
$t_q$		20/25	μs
$t_{rr}$		2	
$V_{DRM}/V_{RRM}$		800/1200	V
$T_J$	Range	- 40 to 125	°C

**ELECTRICAL SPECIFICATIONS**
**VOLTAGE RATINGS**

TYPE NUMBER	VOLTAGE CODE	$V_{RRM}/V_{DRM}$ , MAXIMUM REPETITIVE PEAK REVERSE AND OFF-STATE BLOCKING VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}/I_{DRM}$ AT $T_J = 125^\circ\text{C}$ mA
VSK.F200-	08	800	800	50
	12	1200	1200	

CURRENT CARRYING CAPABILITY							
FREQUENCY							UNITS
50 Hz	380	560	630	850	2460	3180	A
400 Hz	460	690	710	1060	1570	2080	
2500 Hz	310	450	530	760	630	860	
5000 Hz	250	360	410	560	410	560	
10 000 Hz	180	280	300	410	-	-	
Recovery voltage $V_r$	50	50	50	50	50	50	V
Voltage before turn-on $V_d$	80 % $V_{DRM}$		80 % $V_{DRM}$		80 % $V_{DRM}$		
Rise of on-state current $di/dt$	50	50	-	-	-	-	A/μs
Case temperature	85	60	85	60	85	60	°C
Equivalent values for RC circuit	10/0.47		10/0.47		10/0.47		Ω/μF

ON-STATE CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$	180° conduction, half sine wave		200	A
				85	°C
Maximum RMS on-state current	$I_{T(RMS)}$	As AC switch		444	A
Maximum peak, one-cycle non-repetitive on-state, surge current	$I_{TSM}$	t = 10 ms	No voltage reapplied	7600	
		t = 8.3 ms		8000	
		t = 10 ms	100 % $V_{RRM}$ reapplied	6400	
		t = 8.3 ms		6700	
Maximum $I^2t$ for fusing	$I^2t$	t = 10 ms	No voltage reapplied	290	kA <sup>2</sup> s
		t = 8.3 ms		265	
		t = 10 ms	100 % $V_{RRM}$ reapplied	205	
		t = 8.3 ms		187	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied		2900	kA <sup>2</sup> √s
Low level value or threshold voltage	$V_{T(TO)1}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ , $T_J = T_J$ maximum)		1.18	V
High level value of threshold voltage	$V_{T(TO)2}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ , $T_J = T_J$ maximum)		1.25	
Low level value on-state slope resistance	$r_{t1}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ , $T_J = T_J$ maximum)		0.74	mΩ
High level value on-state slope resistance	$r_{t2}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ , $T_J = T_J$ maximum)		0.70	
Maximum on-state voltage drop	$V_{TM}$	$I_{pk} = 600$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sine pulse		1.73	V
Maximum holding current	$I_H$	$T_J = 25$ °C, $I_T > 30$ A		600	mA
Maximum latching current	$I_L$	$T_J = 25$ °C, $V_A = 12$ V, $R_a = 6$ Ω, $I_g = 1$ A		1000	



SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES		UNITS
			K	J	
Maximum non-repetitive rate of rise	$di/dt$	Gate drive 20 V, 20 $\Omega$ , $t_r \leq 1$ ms, $V_D = 80\%$ $V_{DRM}$ , $T_J = 25$ °C	800		A/ $\mu$ s
Maximum recovery time	$t_{rr}$	$I_{TM} = 350$ A, $di/dt = -25$ A/ $\mu$ s, $V_R = 50$ V, $T_J = 25$ °C	2		$\mu$ s
Maximum turn-off time	$t_q$	$I_{TM} = 750$ A; $T_J = T_J$ maximum; $di/dt = -25$ A/ $\mu$ s; $V_R = 50$ V; $dV/dt = 400$ V/ $\mu$ s linear to 80 % $V_{DRM}$	20	25	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	$dV/dt$	$T_J = 125$ °C, exponential to 67 % $V_{DRM}$	1000	V/ $\mu$ s
RMS insulation voltage	$V_{INS}$	50 Hz, circuit to base, $T_J = 25$ °C, $t = 1$ s	3000	V
Maximum peak reverse and off-state leakage current	$I_{RRM}$ , $I_{DRM}$	$T_J = 125$ °C, rated $V_{DRM}/V_{RRM}$ applied	50	mA

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$	$f = 50$ Hz, $d\% = 50$	60	W
Maximum peak average gate power	$P_{G(AV)}$	$T_J = 125$ °C, $f = 50$ Hz, $d\% = 50$	10	
Maximum peak positive gate current	$I_{GM}$	$T_J = 125$ °C, $t_p \leq 5$ ms	10	A
Maximum peak negative gate voltage	$-V_{GT}$		5	V
Maximum DC gate current required to trigger	$I_{GT}$	$T_J = 25$ °C, $V_{ak} 12$ V, $R_a = 6$	200	mA
DC gate voltage required to trigger	$V_{GT}$		3	V
DC gate current not to trigger	$I_{GD}$	$T_J = 125$ °C, rated $V_{DRM}$ applied	20	mA
DC gate voltage not to trigger	$V_{GD}$		0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	$T_J$		- 40 to 125	°C
Storage temperature range	$T_{Stg}$		- 40 to 150	
Maximum thermal resistance, junction to case per junction	$R_{thJC}$	DC operation	0.125	K/W
Maximum thermal resistance, case to heatsink per module	$R_{thC-hs}$	Mounting surface flat, smooth and greased	0.025	
Mounting torque $\pm 10\%$	MAP to heatsink	A mounting compound is recommended. The torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Use of cable lugs is not recommended, busbar should be used and restrained during tightening. Threads must be lubricated with a compound.	4 to 6	N · m (lb · in)
	busbar to MAP		(35 to 53)	
Approximate weight			500	g
			17.8	oz.
Case style			MAGN-A-PAK	

$\Delta R_{thJC}$ CONDUCTION			
CONDUCTIONS ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	UNITS
180°	0.009	0.006	K/W
120°	0.10	0.011	
90°	0.014	0.015	
60°	0.020	0.020	
30°	0.32	0.033	

**Note**

- Table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC



Fig. 1 - Current Ratings Characteristics



Fig. 3 - On-State Power Loss Characteristics



Fig. 2 - Current Ratings Characteristics

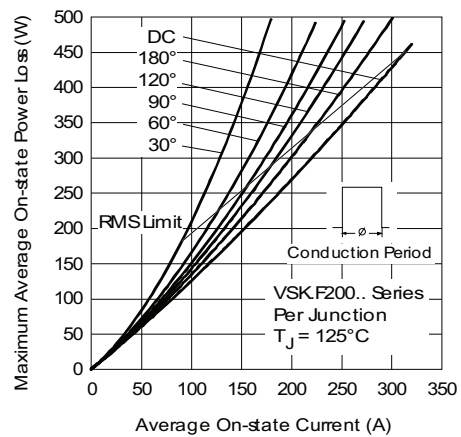


Fig. 4 - On-State Power Loss Characteristics



Fig. 5 - Maximum Non-Repetitive Surge Current



Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics



Fig. 6 - Maximum Non-Repetitive Surge Current



Fig. 9 - Reverse Recovery Charge Characteristics

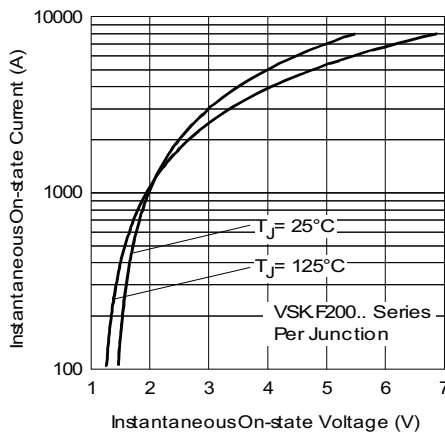


Fig. 7 - On-State Voltage Drop Characteristics



Fig. 10 - Reverse Recovery Current Characteristics

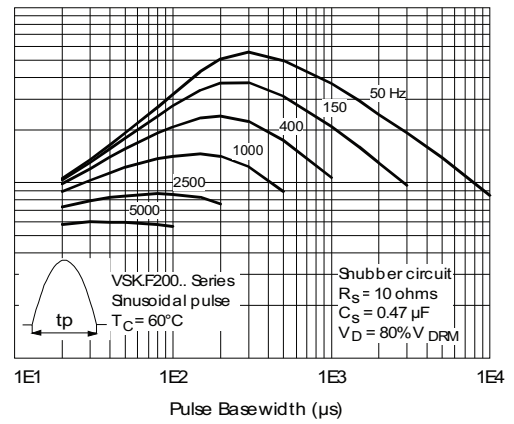
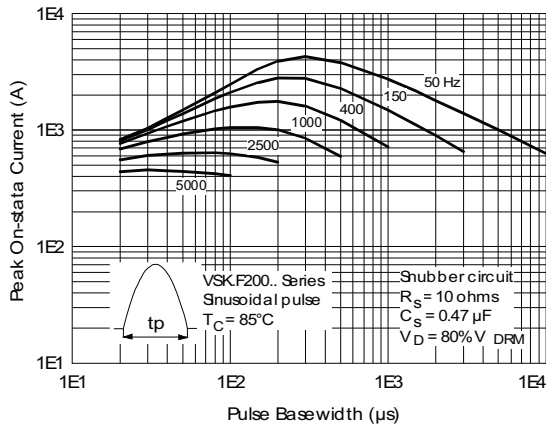


Fig. 11 - Frequency Characteristics

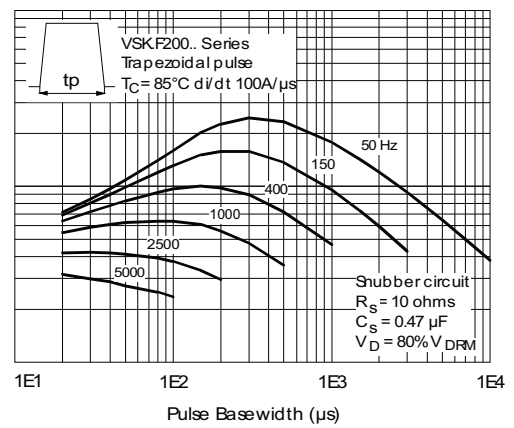
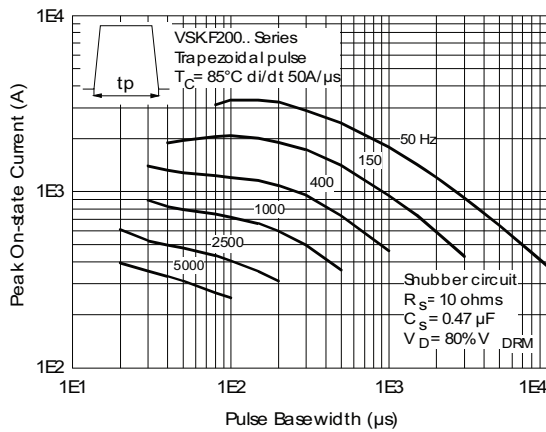


Fig. 12 - Frequency Characteristics

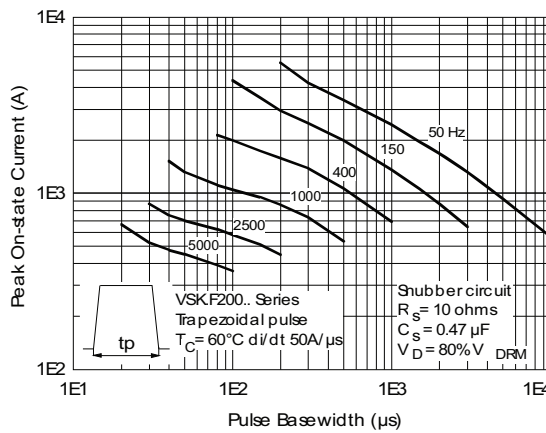


Fig. 13 - Frequency Characteristics

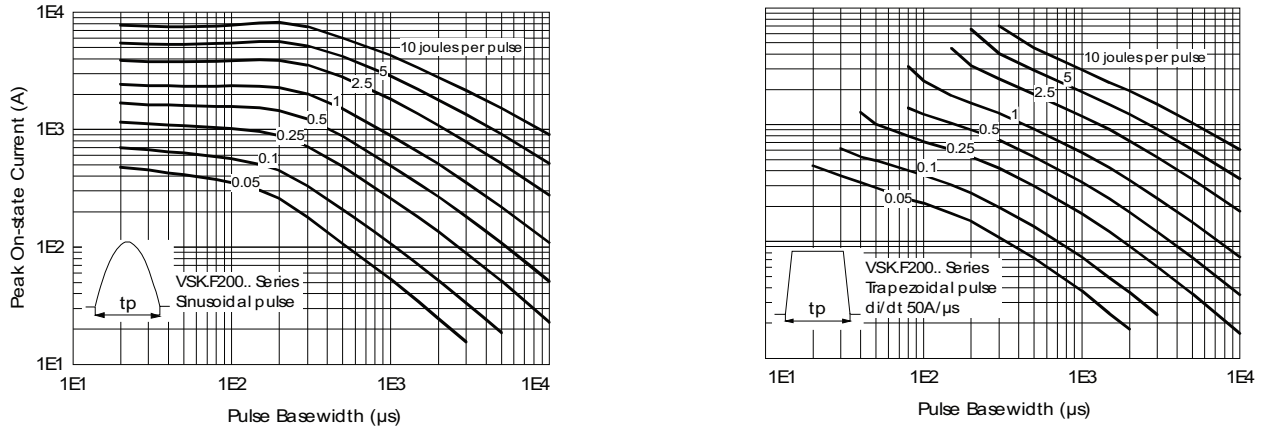


Fig. 14 - Maximum On-State Energy Power Loss Characteristics



Fig. 15 - Gate Characteristics

# VSK.F200..P Series



Vishay Semiconductors Fast Thyristor/Diode and Thyristor/Thyristor  
(MAGN-A-PAK Power Modules), 200 A

## ORDERING INFORMATION TABLE

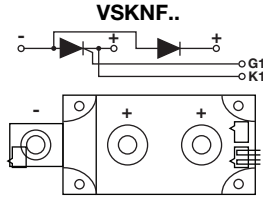
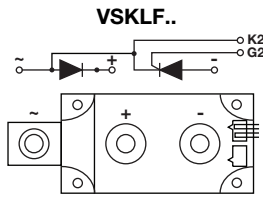
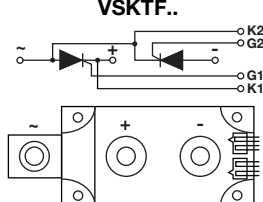
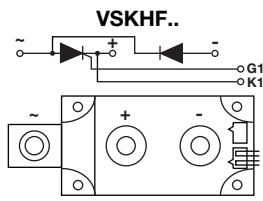
Device code	<b>VSK</b>	<b>T</b>	<b>F</b>	<b>200</b>	<b>-</b>	<b>12</b>	<b>H</b>	<b>K</b>	<b>P</b>
	①	②	③	④		⑤	⑥	⑦	⑧
	<b>1</b>	-	Module type						
	<b>2</b>	-	Circuit configuration (see circuit configuration table)						
	<b>3</b>	-	Fast SCR						
	<b>4</b>	-	Current rating: $I_{T(AV)} \times 10$ rounded						
	<b>5</b>	-	Voltage code $\times 100 = V_{RRM}$ (see Voltage Ratings table)						
	<b>6</b>	-	dV/dt code: $H \leq 400 \text{ V}/\mu\text{s}$						
	<b>7</b>	-	$t_q$ code: $K \leq 20 \mu\text{s}$ $J \leq 25 \mu\text{s}$						
	<b>8</b>	-	Lead (Pb)-free						

### Note

- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)

CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two SCRs common cathodes	U	<p><b>VSKUF..</b></p>
SCR/diode common cathodes	K	<p><b>VSKKF..</b></p>
Two SCRs common anodes	V	<p><b>VSKVF..</b></p>



<b>CIRCUIT CONFIGURATION</b>		
<b>CIRCUIT DESCRIPTION</b>	<b>CIRCUIT CONFIGURATION CODE</b>	<b>CIRCUIT DRAWING</b>
SCR/diode common anodes	N	 <p><b>VSKNF..</b></p>
SCR/diode doubler circuit, negative control	L	 <p><b>VSKLF..</b></p>
Two SCRs doubler circuit	T	 <p><b>VSKTF..</b></p>
SCR/diode doubler circuit, positive control	H	 <p><b>VSKHF..</b></p>

<b>LINKS TO RELATED DOCUMENTS</b>	
Dimensions	<a href="http://www.vishay.com/doc?95086">www.vishay.com/doc?95086</a>

## MAGN-A-PAK

**DIMENSIONS** in millimeters (inches)



### Notes

- Dimensions are nominal
- Full engineering drawings are available on request
- UL identification number for gate and cathode wire: UL 1385
- UL identification number for package: UL 94 V-0



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